

SANYO Semiconductors DATA SHEET

2SK3748 — High-Voltage, High-Speed Switching Applications

Features

- · Low ON-resistance, low input capacitance, ultrahigh-speed switching.
- · High reliability (Adoption of HVP process).
- · Attachment workability is good by Mica-less package.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		1500	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID*		4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	8	Α
Allowable Power Dissipation	D-		3.0	W
	PD	Tc=25°C	65	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		170	mJ
Avalanche Current *2	IAV		4	Α

^{*}Shows chip capability

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0V	1500			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =1200V, V _{GS} =0V			100	μΑ
Gate-to-Source Leakage Current	IGSS	VGS= ±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2.5		3.5	V
Forward Transfer Admittance	yfs	V _{DS} =20V, I _D =2A	1.7	2.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)	ID=2A, VGS=10V		5	7	Ω

Marking: K3748 Continued on next page.

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^{*1} V_{DD}=99V, L=20mH, I_{AV}=4A

^{*2} L≤20mH, single pulse

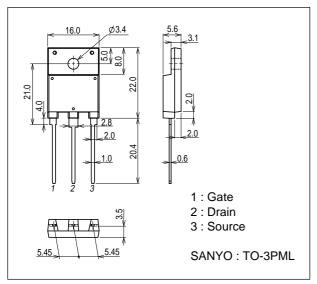
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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =30V, f=1MHz		790		pF
Output Capacitance	Coss	V _{DS} =30V, f=1MHz		140		pF
Reverse Transfer Capacitance	Crss	VDS=30V, f=1MHz		70		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		17		ns
Rise Time	t _r	See specified Test Circuit.		75		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		360		ns
Fall Time	tf	See specified Test Circuit.		116		ns
Total Gate Charge	Qg	V _{DS} =200V, V _{GS} =10V, I _D =4A		80		nC
Gate-to-Source Charge	Qgs	VDS=200V, VGS=10V, ID=4A		6.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =200V, V _{GS} =10V, I _D =4A		36		nC
Diode Forward Voltage	V _{SD}	I _S =4A, V _G S=0V		0.94	1.2	V
Reverse Recovery Time	t _{rr}	IS=4A, VGS=0V, dis/dt=100A/μs		340		ns

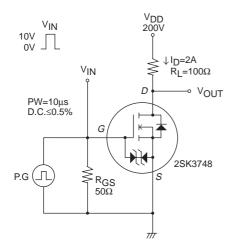
Note) Although the protection diode is contained between gate and source, be careful of handling enough.

Package Dimensions

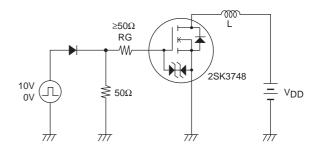
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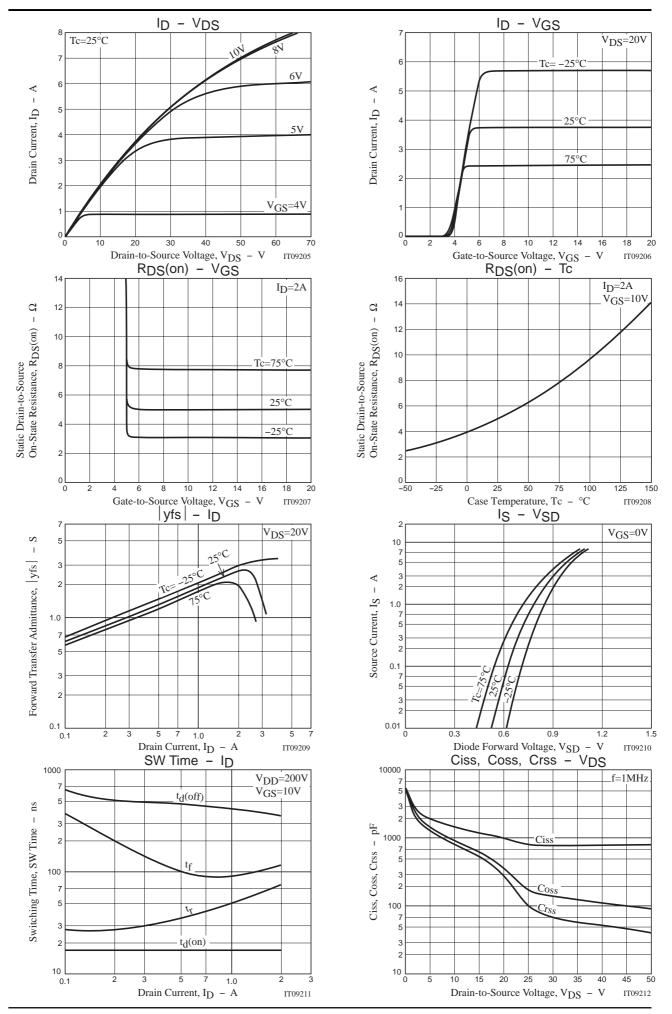


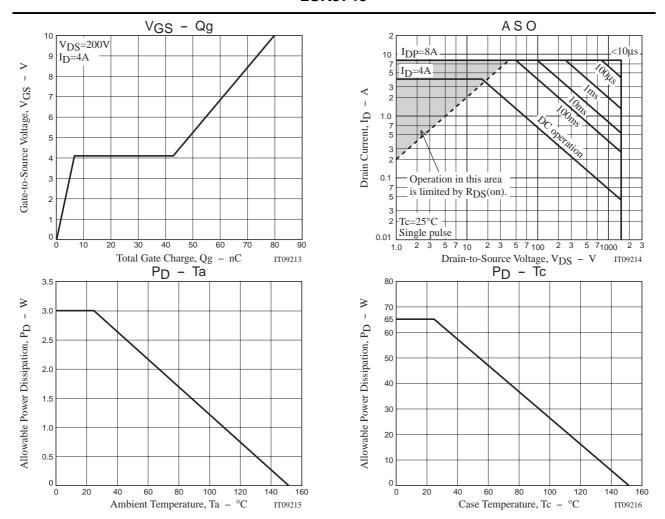
Switching Time Test Circuit



Avalanche Resistance Test Circuit







Note on usage: Since the 2SK3748 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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